RoHS COMPLIANT

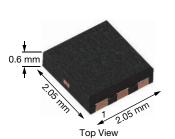
**HALOGEN** 

FREE

Vishay Siliconix

# P-Channel 20 V (D-S) MOSFET

### Thin PowerPAK® SC-70-6L Single





Marking code: BP

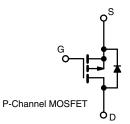
PRODUCT SUMMARY									
V <sub>DS</sub> (V)	-20								
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS} = -4.5 \text{ V}$	0.0205								
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS}$ = -2.5 V	0.0270								
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS} = -1.8 \text{ V}$	0.0360								
$R_{DS(on)}$ max. ( $\Omega$ ) at $V_{GS} = -1.5 \text{ V}$	0.0600								
Q <sub>g</sub> typ. (nC)	24.5								
I <sub>D</sub> (A) <sup>a</sup>	-12								
Configuration	Single								

#### **FEATURES**

- TrenchFET® power MOSFET
- New thermally enhanced PowerPAK® SC-70 package
  - Small footprint area
  - Ultra-thin 0.6 mm height
  - Low on-resistance
- 100 % R<sub>g</sub> tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **APPLICATIONS**

- · Load switch and charger switch for portable devices
- DC/DC converter



ORDERING INFORMATION	
Package	Thin PowerPAK SC-70
Lead (Pb)-free and halogen-free	SiA429DJT-T1-GE3

PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-source voltage		$V_{DS}$	-20	V		
Gate-source voltage		$V_{GS}$	± 8	V		
	T <sub>C</sub> = 25 °C		-12 <sup>a</sup>			
Continuous drain surrent (T. 150 °C)	T <sub>C</sub> = 70 °C	1 , [	-12 <sup>a</sup>			
Continuous drain current (T <sub>J</sub> = 150 °C)	T <sub>A</sub> = 25 °C	I <sub>D</sub>	-10.6 <sup>b, c</sup>			
	T <sub>A</sub> = 70 °C		-8.5 <sup>b, c</sup>	Α		
Pulsed drain current (t = 300 μs)	•	I <sub>DM</sub>	-30	٦		
Outline and an advisor of the country	T <sub>C</sub> = 25 °C	,	-12 <sup>a</sup>			
Continuous source-drain diode current	T <sub>A</sub> = 25 °C	I <sub>S</sub>	-2.9 <sup>b, c</sup>			
	T <sub>C</sub> = 25 °C		19			
Maximum power dissipation	T <sub>C</sub> = 70 °C		12	10/		
	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3.5 b, c	W		
	T <sub>A</sub> = 70 °C		2.2 b, c			
Operating junction and storage temperature ra	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C			
Soldering recommendations (peak temperature		260	7			

THERMAL RESISTANCE RATINGS									
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT				
Maximum junction-to-ambient b, f	t ≤ 5 s	$R_{thJA}$	28	36	°C/W				
Maximum junction-to-case (drain)	Steady state	$R_{thJC}$	5.3	6.5	C/W				

#### **Notes**

- a. Package limited
- b. Surface mounted on 1" x 1" FR4 board
- d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components f. Maximum under steady state conditions is 80 °C/M
- Maximum under steady state conditions is 80 °C/W

# Vishay Siliconix

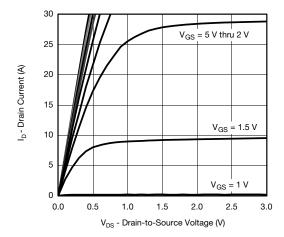
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static				•		
Drain-source breakdown voltage	$V_{DS}$	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-20	-	-	V
V <sub>DS</sub> temperature coefficient	$\Delta V_{DS}/T_{J}$		-	-12	-	1400
V <sub>GS(th)</sub> temperature coefficient	$\Delta V_{GS(th)}/T_J$	I <sub>D</sub> = -250 μA	-	2.7	-	mV/°(
Gate-source threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = -250 \mu A$	-0.4	-	-1	V
Gate-source leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$	-	-	± 100	nA
Zana a da calla da		$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	-1	μΑ
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = -20 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C	-	-	-10	
On-state drain current a	I <sub>D(on)</sub>	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-20	-	-	Α
		$V_{GS} = -4.5 \text{ V}, I_D = -6 \text{ A}$	-	0.0170	0.0205	
Duning and the seriet and 3		$V_{GS} = -2.5 \text{ V}, I_D = -2 \text{ A}$	-	0.0220	0.0270	0
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -1.8 \text{ V}, I_D = -2 \text{ A}$	-	0.0290	0.0360	Ω
		V <sub>GS</sub> = -1.5 V, I <sub>D</sub> = -1 A	-	0.0380	0.0600	
Forward transconductance a	9 <sub>fs</sub>	$V_{DS} = -10 \text{ V}, I_{D} = -6 \text{ A}$	-	30	-	S
Dynamic <sup>b</sup>						
Input capacitance	C <sub>iss</sub>		-	1750	-	pF
Output capacitance	C <sub>oss</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	270	-	
Reverse transfer capacitance	C <sub>rss</sub>		-	240	-	
<b>+</b>	Q <sub>g</sub>	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = -8 V, I <sub>D</sub> = -10 A	-	41	62	nC
Total gate charge			-	24.5	37	
Gate-source charge		$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -10 \text{ A}$	-	2.4	-	
Gate-drain charge	Q <sub>qd</sub>		-	6.7	-	
Gate resistance	R <sub>q</sub>	f = 1 MHz	1.3	6.3	13	Ω
Turn-on delay time	t <sub>d(on)</sub>		-	22	35	
Rise time	t <sub>r</sub>	$V_{DD}$ = -10 V, $R_L$ = 1.2 $\Omega$	-	25	40	
Turn-off delay time	t <sub>d(off)</sub>	$I_D \cong -8.5 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 1 \Omega$	-	70	105	
Fall time	t <sub>f</sub>		-	25	40	
Turn-on delay time	t <sub>d(on)</sub>		-	10	15	ns
Rise time	t <sub>r</sub>	$V_{DD} = -10 \text{ V}, R_L = 1.2 \Omega$		10	15	
Turn-off delay time	t <sub>d(off)</sub>	$I_D \cong -8.5 \text{ A}, V_{GEN} = -8 \text{ V}, R_g = 1 \Omega$	-	80	120	
Fall time	t <sub>f</sub>		-	25	40	
<b>Drain-Source Body Diode Characterist</b>	ics					
Continuous source-drain diode current	I <sub>S</sub>	T <sub>C</sub> = 25 °C	-	-	-12	
Pulse diode forward current	I <sub>SM</sub>		-	-	-30	A
Body diode voltage	$V_{SD}$	I <sub>S</sub> = -8.5 A, V <sub>GS</sub> = 0 V	-	-0.8	-1.2	V
Body diode reverse recovery time	t <sub>rr</sub>		-	35	60	ns
Body diode reverse recovery charge	Q <sub>rr</sub>	$I_F = -8.5 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s},$	-	18	30	nC
Reverse recovery fall time	t <sub>a</sub>	$T_J = 25 ^{\circ}\text{C}$	-	13	-	
Reverse recovery rise time	t <sub>b</sub>		-	22	_	ns

#### **Notes**

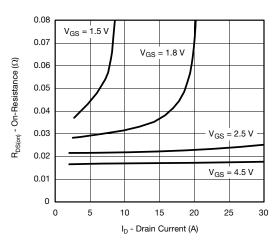
- a. Pulse test; pulse width  $\leq 300~\mu\text{s},$  duty cycle  $\leq 2\%$
- b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

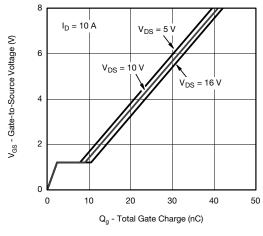




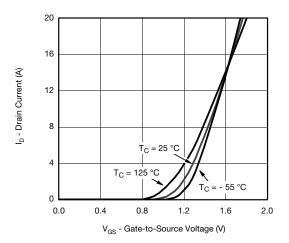
#### **Output Characteristics**



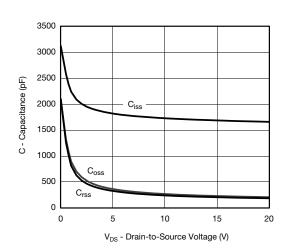
On-Resistance vs. Drain Current and Gate Voltage



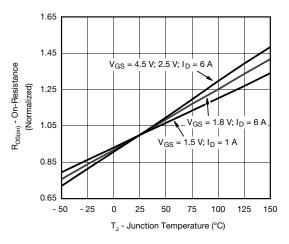
**Gate Charge** 



**Transfer Characteristics** 

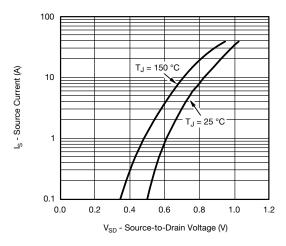


Capacitance

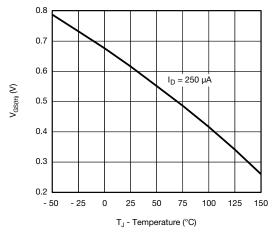


On-Resistance vs. Junction Temperature

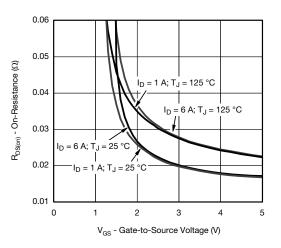




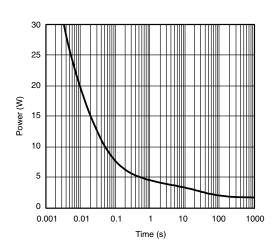
#### Source-Drain Diode Forward Voltage



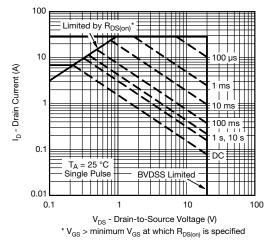
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage

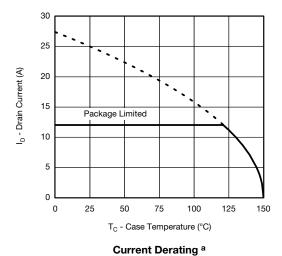


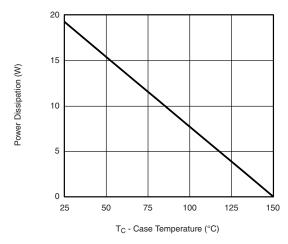
Single Pulse Power, Junction-to-Ambient



Safe Operating Area, Junction-to-Ambient





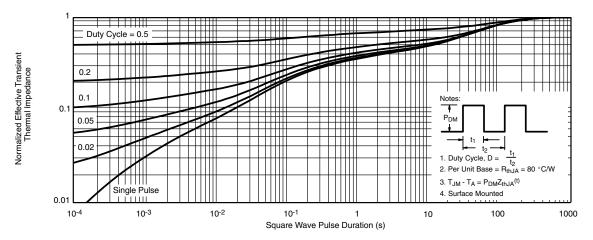


**Power Derating** 

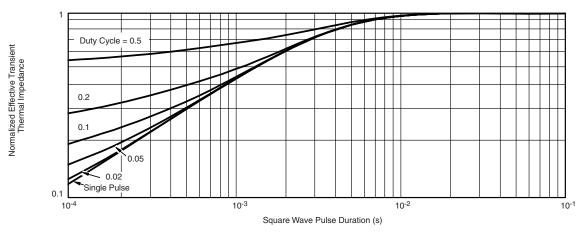
# Note

a. The power dissipation  $P_D$  is based on  $T_J$  max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit





Normalized Thermal Transient Impedance, Junction-to-Ambient



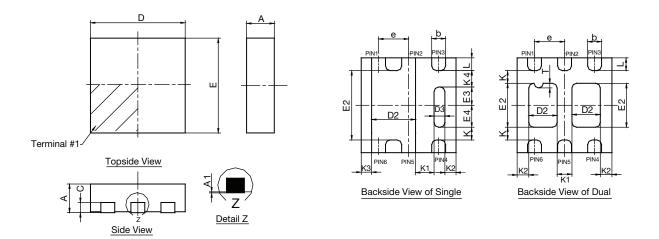
Normalized Thermal Transient Impedance, Junction-to-Case

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# Case Outline for PowerPAK® SC70T



	SINGLE PAD						DUAL PAD						
DIM.	MILLIMETERS			INCHES		MILLIMETERS			INCHES				
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	0.525	0.60	0.65	0.0206	0.024	0.026	0.525	0.60	0.65	0.0206	0.024	0.026	
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002	
b	0.23	0.30	0.38	0.009	0.012	0.015	0.23	0.30	0.38	0.009	0.012	0.015	
С	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010	
D	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085	
D2	0.85	0.95	1.05	0.033	0.037	0.041	0.513	0.613	0.713	0.020	0.024	0.028	
D3	0.135	0.235	0.335	0.005 0.009 0.013									
Е	1.98	2.05	2.15	0.078	0.081	0.085	1.98	2.05	2.15	0.078	0.081	0.085	
E2	1.40	1.50	1.60	0.055	0.059	0.063	0.85	0.95	1.05	0.033	0.037	0.041	
E3	0.345	0.395	0.445	0.014	0.016	0.018							
E4	0.425	0.475	0.525	0.017	0.019	0.021							
е		0.65 BSC			0.026 BSC		0.65 BSC			0.026 BSC			
K		0.275 TYP.			0.011 TYP.			0.275 TYP.			0.011 TYP.		
K1		0.400 TYP.		0.016 TYP.			0.320 TYP.			0.013 TYP.			
K2		0.240 TYP.		0.009 TYP.			0.252 TYP.			0.010 TYP.			
K3		0.225 TYP.		0.009 TYP.									
K4		0.355 TYP.		0.014 TYP.									
L	0.175	0.275	0.375	0.007	0.011	0.015	0.175	0.275	0.375	0.007	0.011	0.015	
Т							0.05	0.10	0.15	0.002	0.004	0.006	

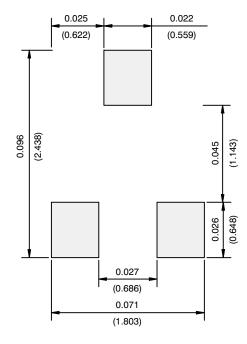
DWG: 5994 60-Rev. B, 05-Mar-12

**Notes** 

- 1. All dimensions are in millimeter. Millimeters will govern.
- 2. Package outline exculsive of mold flash and metal burr.
- 3. Package outline inclusive of plating



### **RECOMMENDED MINIMUM PADS FOR SC-70: 3-Lead**



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



### **RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead**



Recommended Minimum Pads Dimensions in Inches/(mm)

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